

Silicon NPN Power Transistor

DESCRIPTION

- High Collector-Emitter Sustaining Voltage-
- : V_{CEO(SUS)}= 400V (Min)
- · High Switching Speed

APPLICATIONS

- · Power switching
- · Power amplification
- Power driver

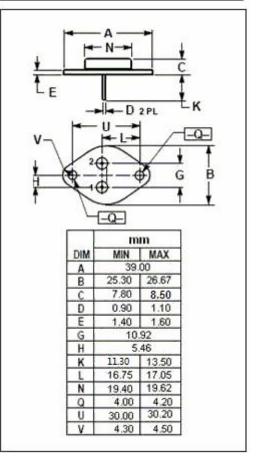
ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | MAX | UNIT | |
|------------------|--|---------|--|--|
| V _{CBO} | Collector-Base Voltage | 450 | V | |
| V _{CEO} | Collector-Emitter Voltage | 400 | V | |
| V _{EBO} | Emitter-Base Voltage | 5 | ٧ | |
| Ic | Collector Current-Continuous | 15 | Α | |
| Ісм | Collector Current-Peak | 30 | А | |
| I _B | Base Current-Continuous | 6 | Α | |
| Pc | Collector Power Dissipation @T _C =25℃ 100 | | W | |
| Tj | Junction Temperature | 200 | $^{\circ}$ | |
| T _{stg} | Storage Temperature Range | -65~200 | $^{\circ}\!$ | |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|---------------------|-------------------------------------|-----|------|
| R _{th j-c} | Thermal Resistance,Junction to Case | 1.0 | °C/W |

PIN 1. BASE 2. BMITTER 3. COLLECTOR (CASE) TO-3 package



Ordering Information

| Product | Package | Packaging | | |
|-------------|---------|-----------|--|--|
| 2SC2246T3BL | TO-3 | Box | | |

V01



ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

| I _C =25 C unless otherwise specified | | | | | | | | |
|---|--------------------------------------|--|-----|------|------------|------------|--|--|
| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT | | |
| V _{CEO(SUS)} | Collector-Emitter Sustaining Voltage | I _C = 50mA; L= 25mH | 400 | | | V | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C = 6A; I _B = 1.2A | | | 1.2 | V | | |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = 6A; I _B = 1.2A | | | 1.5 | V | | |
| h _{FE} | DC Current Gain | I _C = 5A; V _{CE} = 2V | 12 | | 60 | | | |
| h _{FE} | DC Current Gain | I _C = 10A; V _{CE} = 2V | 6 | | 30 | | | |
| Ісво | Collector Cutoff Current | V _{CB} = 450V; I _E = 0 T _C =125℃ | | | 1.0 4.0 | mA | | |
| I _{CEO} | Collector Cutoff Current | V _{CE} = 400V; I _B = 0 | | | 5.0 | mA | | |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 5V; I _C = 0 | | | 1.0 | mA | | |
| Switching Times | | | | | | | | |
| t _r | Rise Time | | | | 1.0 | μs | | |
| t _{stg} | Storage Time | I _C = 6A; I _{B1} =- I _{B2} = 1.2A | | | 2.0 | μ s | | |
| t _f | Fall Time | | | | 1.0 | μs | | |

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